

ROHS

HALOGEN

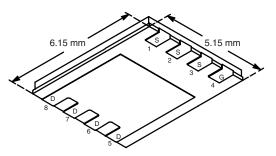
FREE

Vishay Siliconix

N-Channel 200-V (D-S) MOSFET

| PRODUCT SUMMARY | | | | |
|---------------------|--|--------------------|--|--|
| V _{DS} (V) | R_{DS(on)} (Ω) | I _D (A) | | |
| 200 | 0.080 at V _{GS} = 10 V | 5.3 | | |
| | 0.090 at V _{GS} = 6 V | 5.0 | | |

PowerPAK SO-8



Bottom View

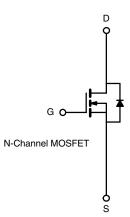
Ordering Information: Si7450DP-T1-E3 (Lead (Pb)-free) Si7450DP-T1-GE3 (Lead (Pb)-free and Halogen-free)

FEATURES

- Halogen-free According to IEC 61249-2-21
 Available
- TrenchFET[®] Power MOSFETs
- New Low Thermal Resistance PowerPAK[®] Package with Low 1.07 mm Profile
- PWM Optimized for Fast Switching
- 100 % R_q Tested

APPLICATIONS

- Primary Side Switch for High Density DC/DC
- Telecom/Server 48 V DC/DC
- Industrial and 42 V Automotive



| Parameter | | Symbol | 10 s | Steady State | Unit |
|--|------------------------|-----------------------------------|-------------|--------------|------|
| Drain-Source Voltage | | V _{DS} | 200 | | V |
| Gate-Source Voltage | | V _{GS} | ± 20 | | v |
| Continuous Drain Current (T 150°C)a | T _A = 25 °C | 1- | 5.3 | 3.2 | |
| Continuous Drain Current (T _J = 150°C) ^a | T _A = 70 °C | ID | 4.3 | 2.6 | |
| Pulsed Drain Current | | I _{DM} | 40 | | A |
| Avalanche Current | | I _{AS} | 15 | | |
| Continuous Source Current (Diode Conduction) ^a | | ۱ _S | 4.3 | 1.6 | |
| | T _A = 25 °C | – P _D | 5.2 | 1.9 | W |
| Maximum Power Dissipation ^a | T _A = 70 °C | | 3.3 | 1.2 | |
| Operating Junction and Storage Temperature Range | | T _J , T _{stg} | - 55 to 150 | | °C |
| Soldering Recommendations (Peak Temperature) ^{b, c} | | | 260 | | |

| THERMAL RESISTANCE RATINGS | | | | | |
|--|--------------|---------------------|---------|---------|------|
| Parameter | | Symbol | Typical | Maximum | Unit |
| Maximum Junction-to-Ambient ^a | t ≤ 10 s | - R _{thJA} | 19 | 24 | °C/W |
| Maximum Junction-to-Ambient* | Steady State | | 52 | 65 | |
| Maximum Junction-to-Case (Drain) | Steady State | R _{thJC} | 1.5 | 1.8 | |

Notes:

a. Surface Mounted on 1" x 1" FR4 board.

b. See Solder Profile (<u>www.vishay.com/ppg?73257</u>). The PowerPAK SO-8 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.

c. Rework Conditions: manual soldering with a soldering iron is not recommended for leadless components.

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Turn-On Delay Time

Turn-Off Delay Time

Source-Drain Reverse Recovery

Dynamic^b **Total Gate Charge** Gate-Source Charge Gate-Drain Charge Gate Resistance

Rise Time

Fall Time

| SPECIFICATIONS $T_J = 25 ^{\circ}C$, unless otherwise noted | | | | | | | | |
|---|---------------------|--|------|-------|-------|------|--|--|
| Parameter | Symbol | Test Condition | Min. | Тур. | Max. | Unit | | |
| Static | | | | | | | | |
| Gate Threshold Voltage | V _{GS(th)} | $V_{DS} = V_{GS}, I_D = 250 \ \mu A$ | 2.0 | | 4.5 | V | | |
| Gate-Body Leakage | I _{GSS} | $V_{DS} = 0 V, V_{GS} = \pm 20 V$ | | | ±100 | nA | | |
| Zero Gate Voltage Drain Current | I _{DSS} | $V_{DS} = 200 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$ | | | 1 | μΑ | | |
| | | V_{DS} = 200 V, V_{GS} = 0 V, T_{J} = 55 °C | | | 5 | | | |
| On-State Drain Current ^a | I _{D(on)} | $V_{DS} \! \geq \! 5$ V, V_{GS} = 10 V | 40 | | | А | | |
| Drain-Source On-State Resistance ^a | R _{DS(on)} | $V_{GS} = 10 \text{ V}, \text{ I}_{D} = 4.0 \text{ A}$ | | 0.065 | 0.080 | Ω | | |
| | | $V_{GS} = 6.0 \text{ V}, I_D = 4.0 \text{ A}$ | | 0.070 | 0.090 | | | |
| Forward Transconductance ^a | 9 _{fs} | $V_{DS} = 15 \text{ V}, \text{ I}_{D} = 5 \text{ A}$ | | 19 | | S | | |
| Diode Forward Voltage ^a | V _{SD} | $I_{\rm S}$ = 2.8 A, $V_{\rm GS}$ = 0 V | | 0.75 | 1.2 | V | | |
| Dynamic ^b | | | | | | | | |
| Total Gate Charge | Qg | | | 34 | 42 | nC | | |
| Gate-Source Charge | Q _{gs} | V_{DS} = 100 V, V_{GS} = 10 V, I_{D} = 4.0 A | | 7.5 | | | | |
| Gate-Drain Charge | Q _{gd} | | | 12.0 | | | | |
| | | | + | 1 | | | | |

0.2

0.85

14

20

32

25

70

1.5

20

30

50

35

100

Ω

ns

Time Notes:

a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %. b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

 V_{DD} = 100 V, R_L = 25 Ω $I_D \cong 4.0$ A, $V_{GEN} = 10$ V, $R_a = 6$ Ω

 $I_F = 2.8 \text{ A}, \text{ dI/dt} = 100 \text{ A/}\mu\text{s}$

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

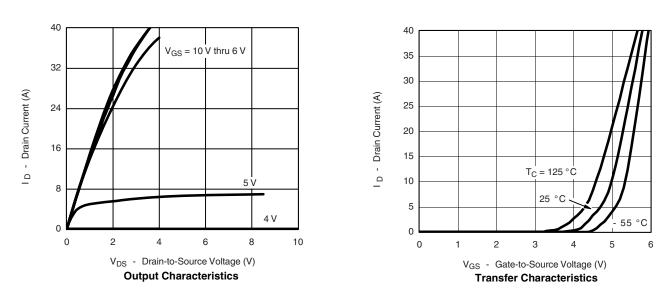
 R_g

t_{d(on)} tr

t_{d(off)}

t_f

t_{rr}



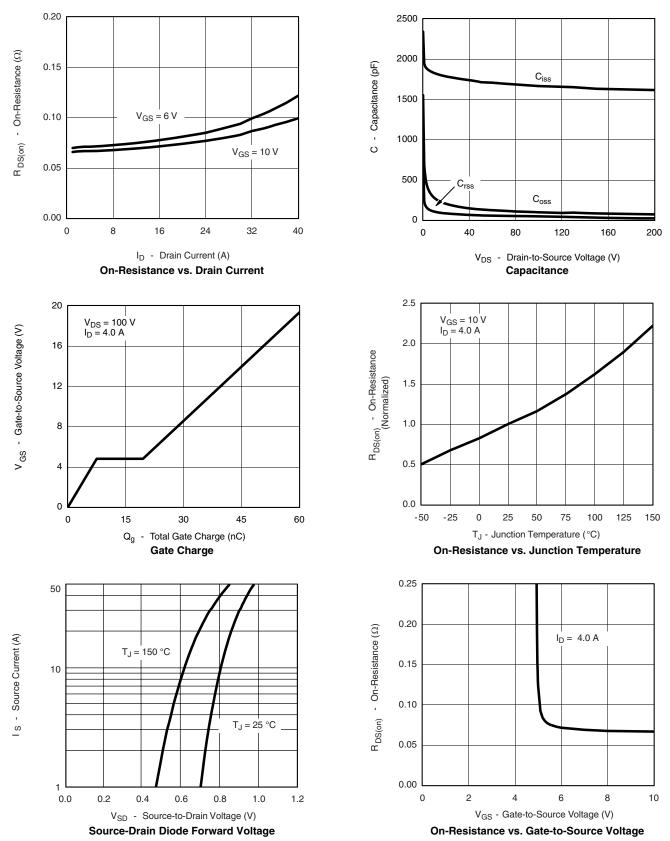
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Si7450DP

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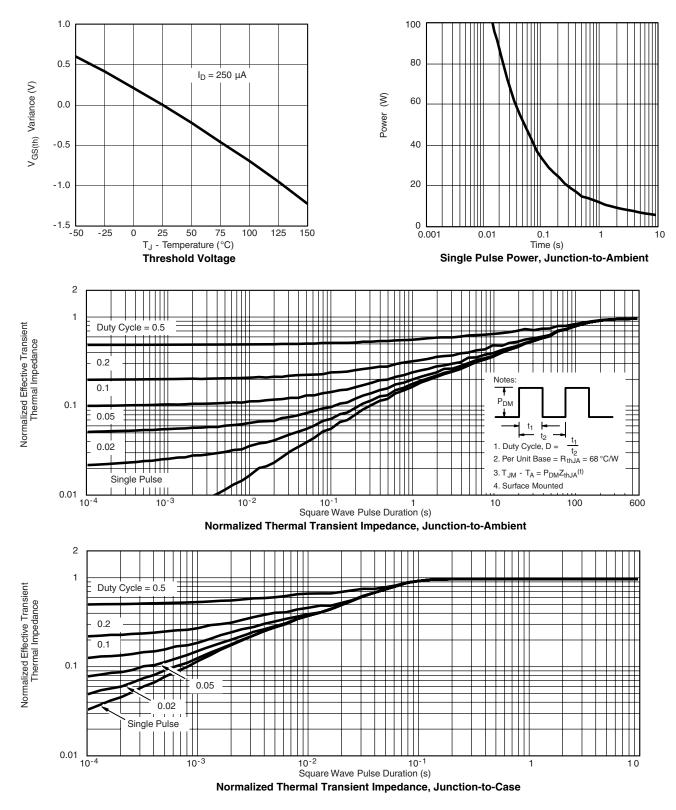


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TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?71432.



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